## MSKSEMI















**ESD** 

TVS

TSS

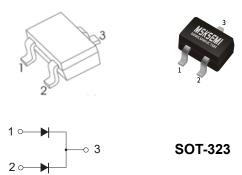
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GDT

**PLED** 

# Broduct data sheet





**MARKING: KJA** 

## **BAV70W** switching DIODE

#### **FEATURES**

- Fast Switching Speed
- For General Purpose Switching Applications
- High Conductance

#### Maximum Ratings @Ta=25℃

Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	$V_{RM}$	100	V
Peak Repetitive Peak Reverse Voltage	$V_{RRM}$		
Working Peak Reverse Voltage	$V_{RWM}$	75	V
DC Blocking Voltage	V <sub>R</sub>		
RMS Reverse Voltage	V <sub>R(RMS)</sub>	53	V
Forward Continuous Current	I <sub>FM</sub>	300	mA
Average Rectified Output Current	Io	150	mA
Non-Repetitive Peak Forward Surge Current @t=8.3ms	I <sub>FSM</sub>	2.0	Α
Power Dissipation	Pd	200	mW
Thermal Resistance Junction to Ambient	$R_{ heta JA}$	625	°C/W
Junction Temperature	Tj	150	$^{\circ}\mathbb{C}$
Storage Temperature	T <sub>STG</sub>	-55~+150	$^{\circ}\mathbb{C}$

#### Electrical Ratings @Ta=25℃

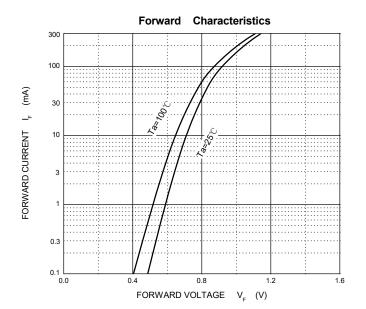
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Reverse breakdown voltage	V <sub>(BR)</sub>	75			V	I <sub>R</sub> =100μA
Forward voltage	V <sub>F1</sub>			0.715	V	I <sub>F</sub> =1mA
	V <sub>F2</sub>			0.855	V	I <sub>F</sub> =10mA
	V <sub>F3</sub>			1.0	V	I <sub>F</sub> =50mA
	V <sub>F4</sub>			1.25	V	I <sub>F</sub> =150mA
B	I <sub>R1</sub>			2.5	μA	V <sub>R</sub> =75V
Reverse current	I <sub>R2</sub>			25	nA	V <sub>R</sub> =20V
Capacitance between terminals	Ст			2	pF	V <sub>R</sub> =0V,f=1MHz
Reverse recovery time	4			4		I <sub>F</sub> =I <sub>R</sub> =10mA
	t <sub>rr</sub>			4	ns	Irr=0.1XI <sub>R</sub> ,R <sub>L</sub> =100Ω

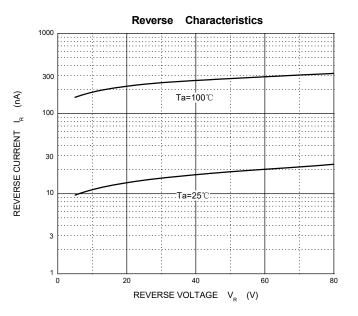


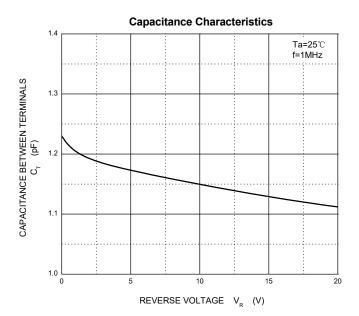
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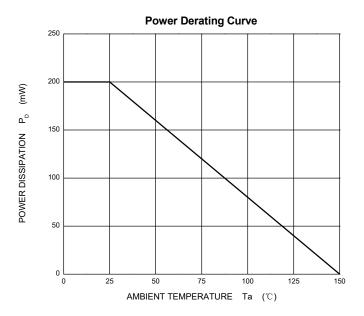
#### Compiance

#### **Typical Characteristics**



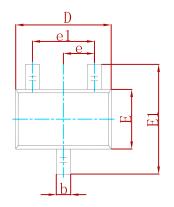


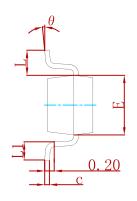


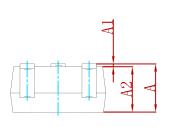




#### **PACKAGE MECHANICAL DATA**

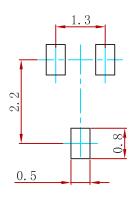






Cumbal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.200	0.400	0.008	0.016	
С	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
Е	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.65	0 TYP	0.026	3 TYP	
e1	1.200	1.400	0.047	0.055	
L	0.52	5 REF	0.02	I REF	
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

## **Suggested Pad Layout**



#### Note:

- 1. Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

#### **REEL SPECIFICATION**

P/N	PKG	QTY
BAV70W	SOT-323	3000



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